

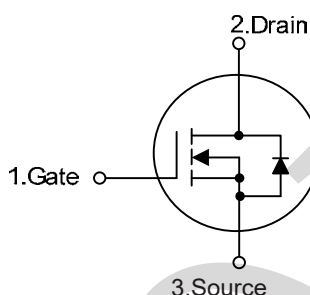
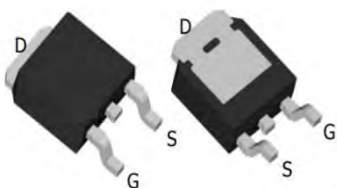
Trench N-channel Power MOSFET

MSR017N06D

TO-252

Top View

Bottom View



V_{DS}	60	V
$R_{DS(on),TYP@ V_{GS}=10V}$	12	mΩ
I_D	50	A

Features

- 1、Low on – resistance
- 2、Package TO-252
- 3、TrenchFET Power MOSFET

Applications

- 1、Load Switch for Portable Devices
- 2、PWM Application
- 3、Power management

Maximum ratings, at $T_A = 25^\circ\text{C}$, unless otherwise specified

Symbol	Parameter		Rating	Unit
V(BR)DSS	Drain-Source breakdown voltage		60	V
VGS	Gate-Source voltage		±20	V
ID	Continuous drain current	T _C = 25°C	50	A
		T _C = 100°C	33	A
IDM	Pulse drain current tested (Note1)	T _C =25°C	200	A
EAS	Avalanche energy, single pulsed (Note2)		64	mJ
PD	Maximum power dissipation	T _C =25°C	89	W
TSTG,TJ	Storage and Junction Temperature Range		-55 to +175	°C

Thermal Characteristics

Symbol	Parameter	Typical	Unit
R _{θJC}	Thermal Resistance, Junction-to-Case	1.69	°C/W

Electrical Characteristics

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
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Static Electrical Characteristics @T_j=25°C (unless otherwise stated)

V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	60	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =60V, V _{GS} =0V, T _j =25°C	--	--	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	1.6	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance (Note3)	V _{GS} =10V, I _D =30A	--	12	17	mΩ
		V _{GS} =4.5V, I _D =20A	--	16	25	mΩ

Dynamic Electrical Characteristics@T_j = 25°C (unless otherwise stated)

C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} =25V, f=1.0MHz	--	2900	--	pF
C _{oss}	Output Capacitance		--	140	--	pF
C _{rss}	Reverse Transfer Capacitance		--	124	--	pF
Q _g	Total Gate Charge	V _{GS} =10V, V _{DS} =30V, I _D =30A	--	70	--	nC
Q _{gs}	Gate-Source Charge		--	6	--	nC
Q _{gd}	Gate-Drain Charge		--	15	--	nC

Switching Characteristics

Td(on)	Turn-on Delay Time	V _{DS} =25V, I _D =30A, R _G =1.8Ω, V _{GS} =10V	--	7.4	--	ns
Tr	Turn-on Rise Time		--	5.1	--	ns
Td(off)	Turn-Off Delay Time		--	28.2	--	ns
Tf	Turn-Off Fall Time		--	5.5	--	ns

Source -Drain Diode Characteristics @T_j = 25°C (unless otherwise stated)

I _S	Maximum Continuous Drain to Source Diode Forward Current		--	--	50	A
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		--	--	200	A
V _{SD}	Forward on voltage	I _S =30A, V _{GS} =0V	--	--	1.2	V
T _{rr}	Reverse Recovery Time	I _F =30A , di/dt=100A/μs	--	28	--	ns
Q _{rr}	Reverse Recovery Charge		--	40	--	nC

NOTE: 1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature.

2. E_{AS} condition : T_J=25 °C, V_{DD}=30V, V_G=10V, L=0.5mH, R_G=25Ω, I_{AS}=16A.

3. Pulse Test: Pulse Width≤300μs, Duty Cycle≤0.5%.

Typical Characteristics

Figure1: Output Characteristics

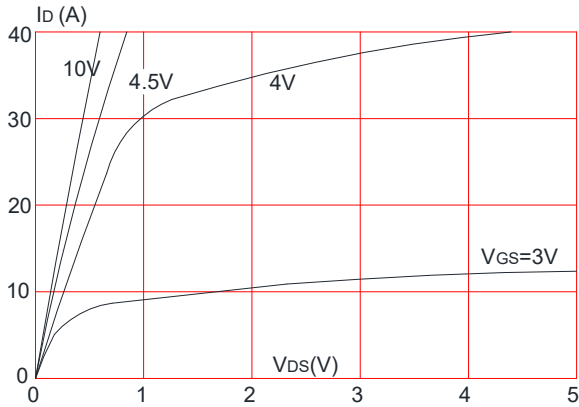


Figure 2: Typical Transfer Characteristics

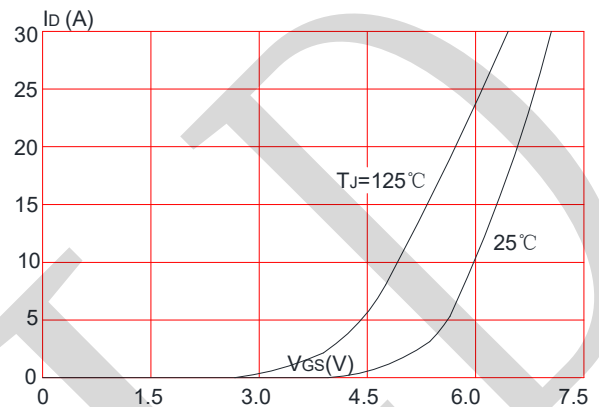


Figure 3: On-resistance vs. Drain Current

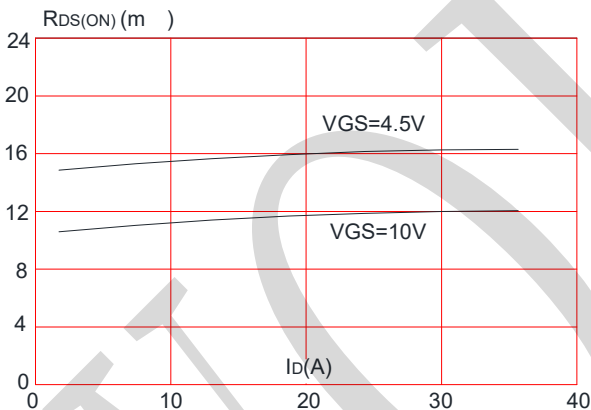


Figure 4: Body Diode Characteristics

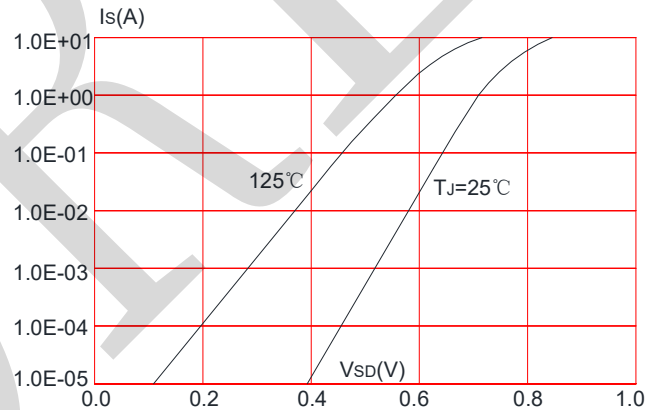


Figure 5: Gate Charge Characteristics

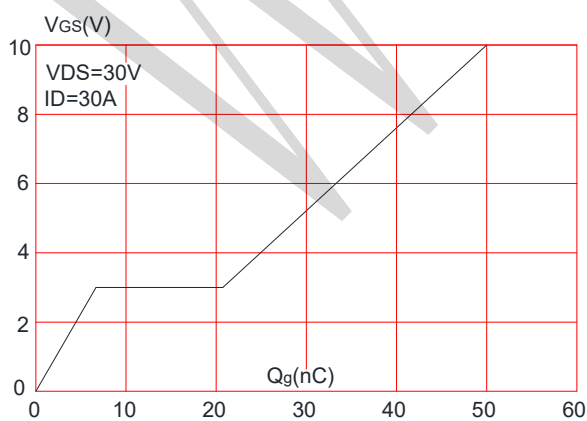
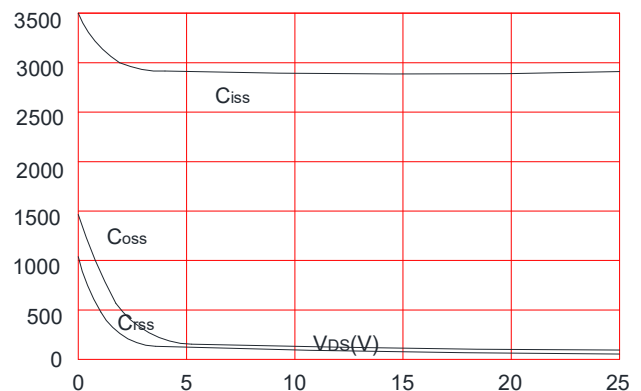


Figure 6: Capacitance Characteristics



Typical Characteristics

Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

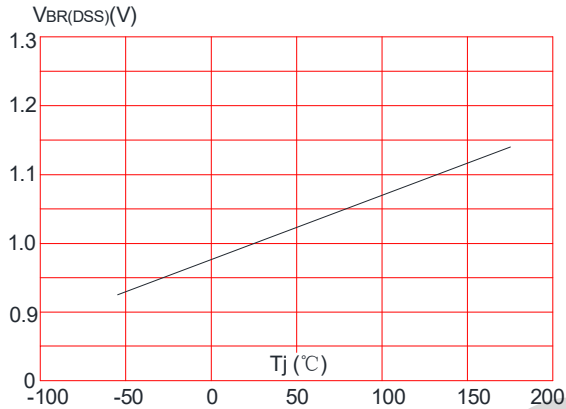


Figure 8: Normalized on Resistance vs. Junction Temperature

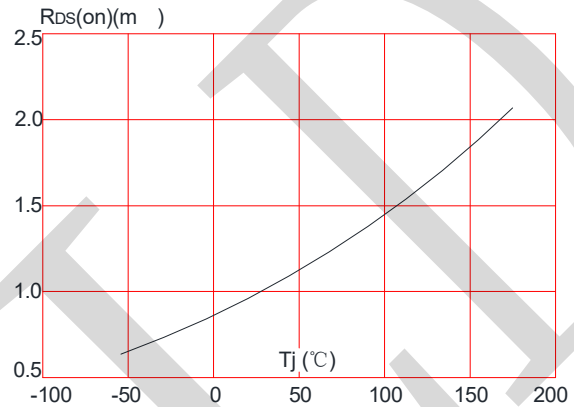


Figure 9: Maximum Safe Operating Area

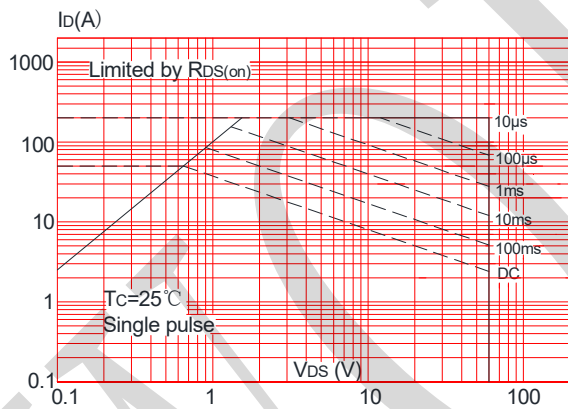


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

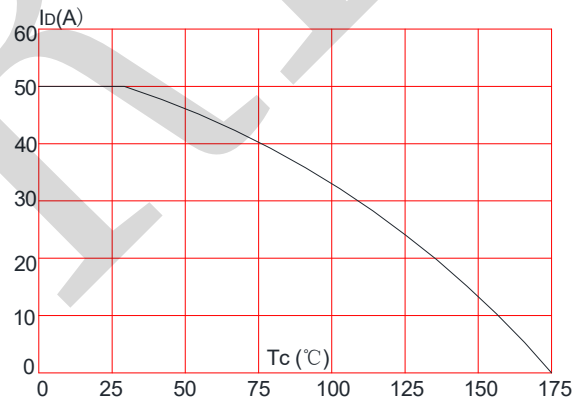
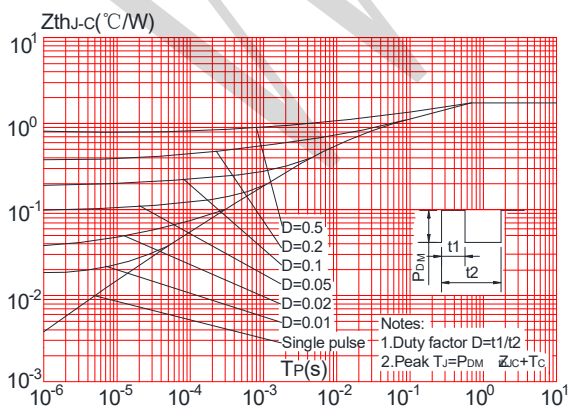


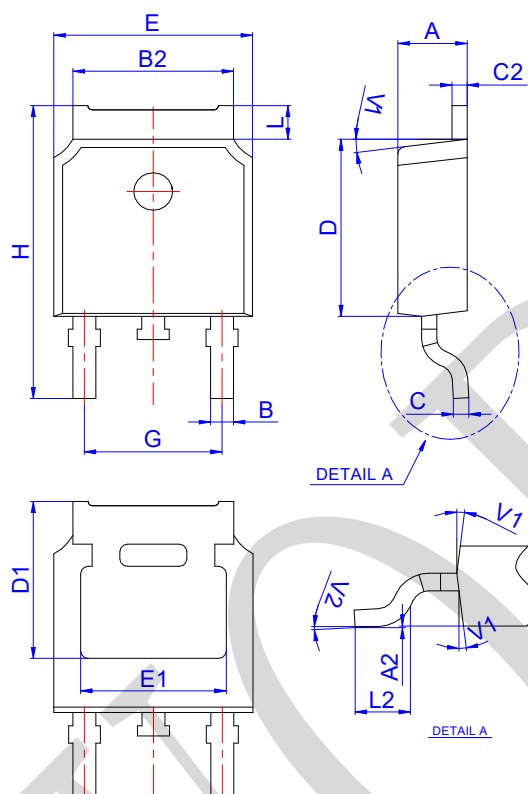
Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Case



PACKAGE OUTLINE DIMENSIONS

Note:unit mm

TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°